



DOCKET NO: 246155US2SRD

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :  
MASATO KOYAMA, ET AL. : EXAMINER: HU, S.  
SERIAL NO: 10/726,705 :  
FILED: DECEMBER 4, 2003 : GROUP ART UNIT: 2811  
FOR: A METHOD OF FORMING A :  
SEMICONDUCTOR DEVICE HAVING  
AN AMORPHOUS/CRYSTALLINE GATE  
INSULATING LAYER

AMENDMENT UNDER 37 C.F.R. § 1.111

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated September 20, 2005, please amend the above-identified application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins on page 2 of this paper.

**Remarks/Arguments** begin on page 5 of this paper.